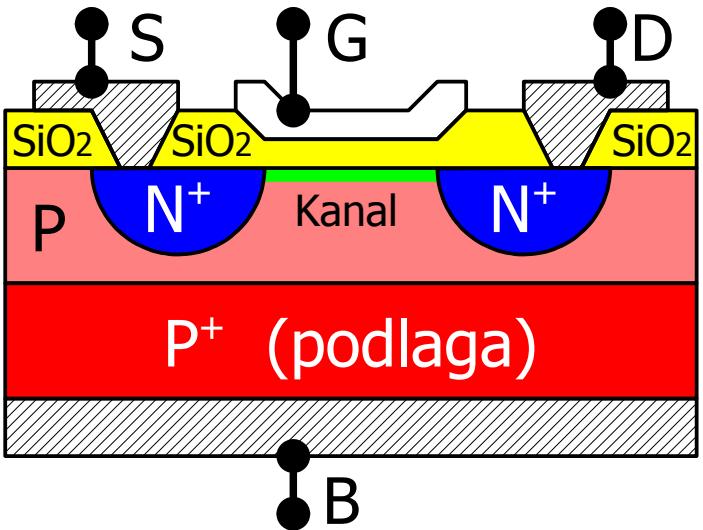
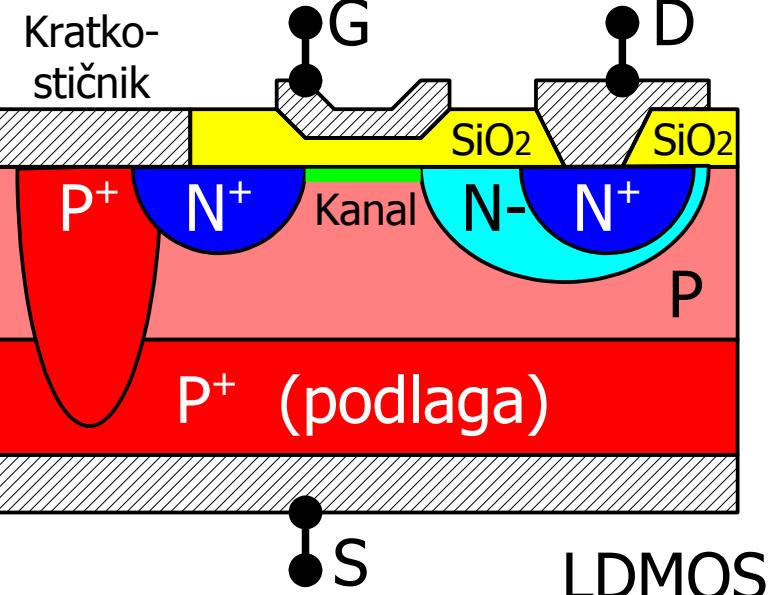
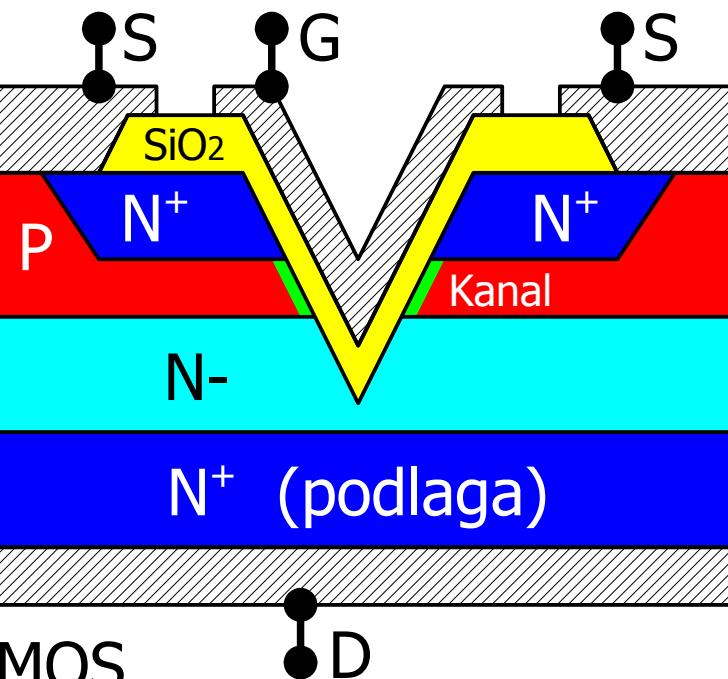
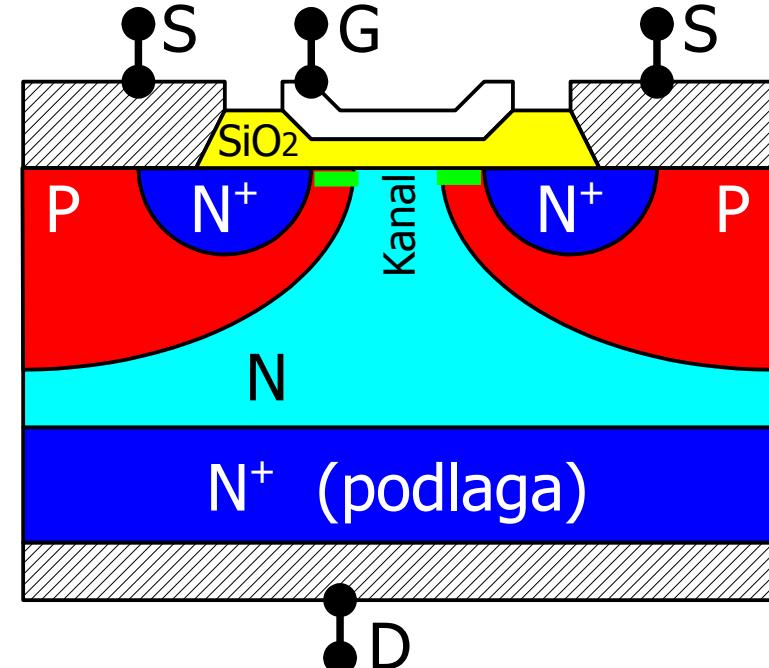


Malosignalni MOSFET



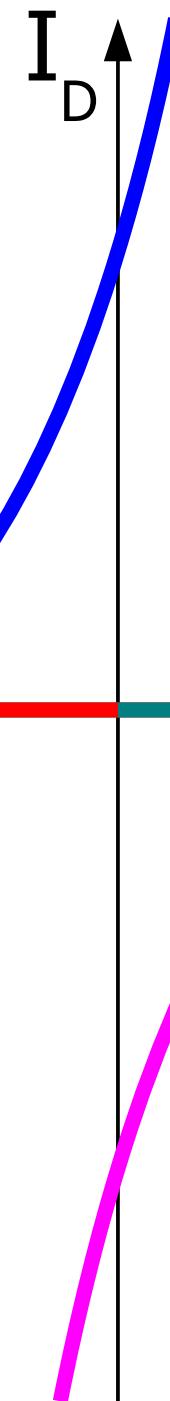
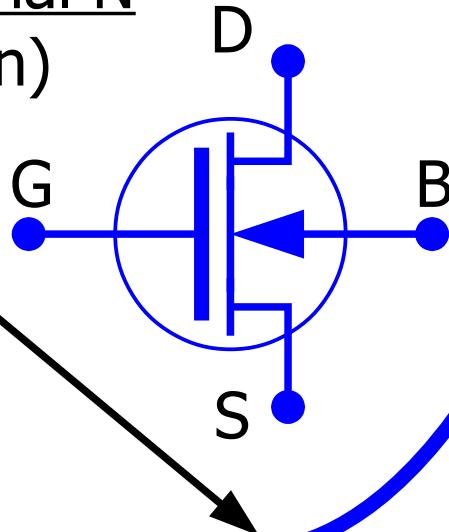
Močnostni MOSFET



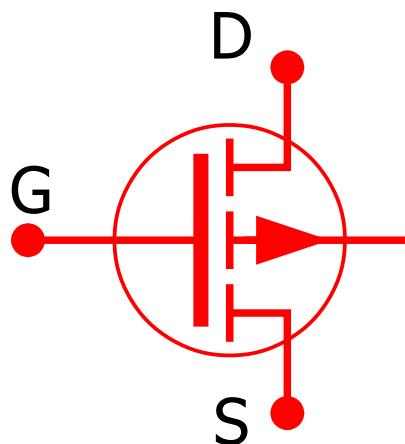
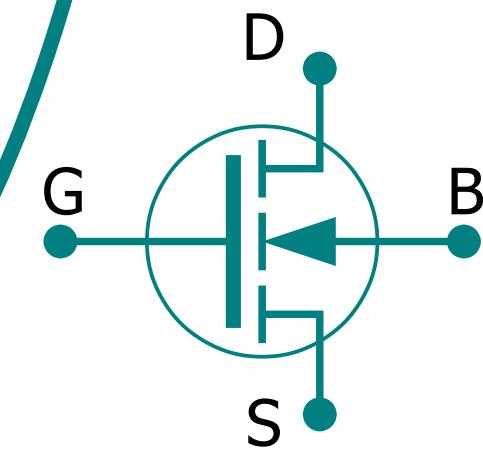
Izvedbe MOS tranzistorjev

Siromašeni kanal N

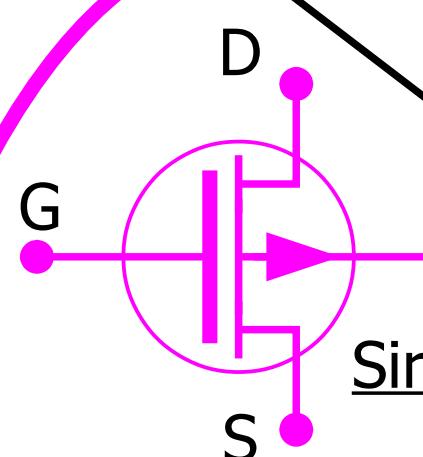
(N-depletion)



Inducirani kanal N
(N-enhancement)



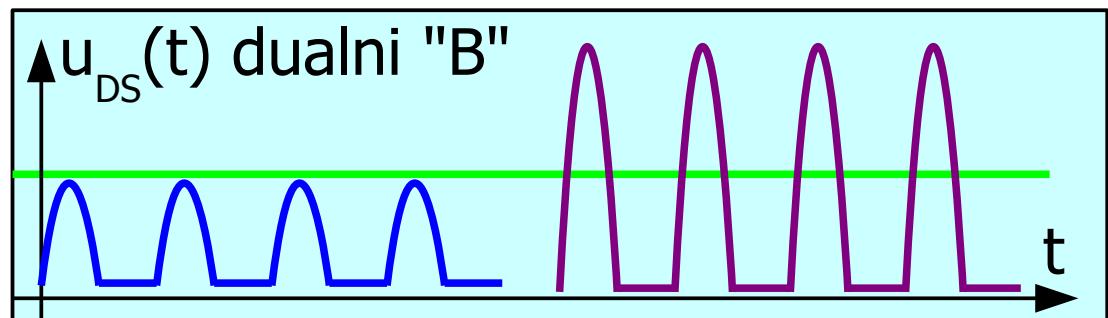
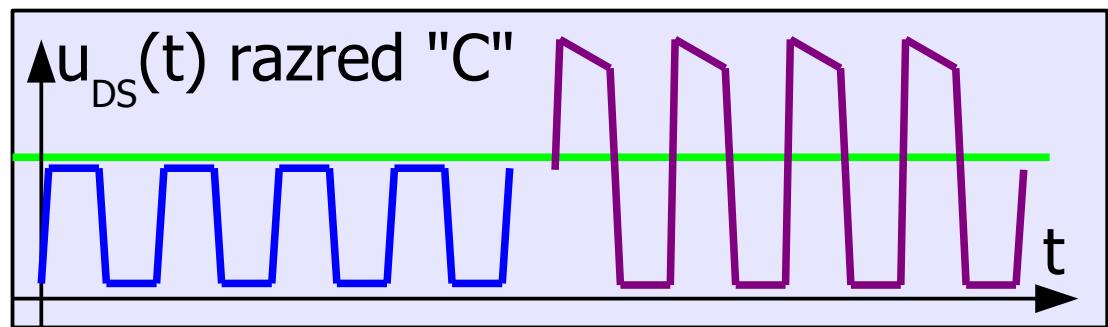
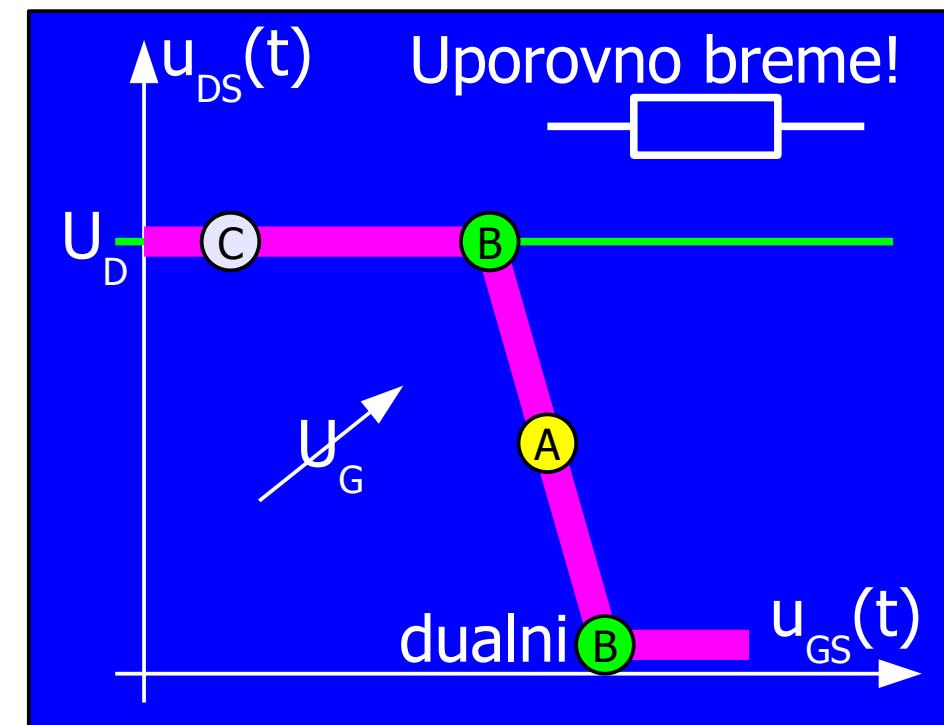
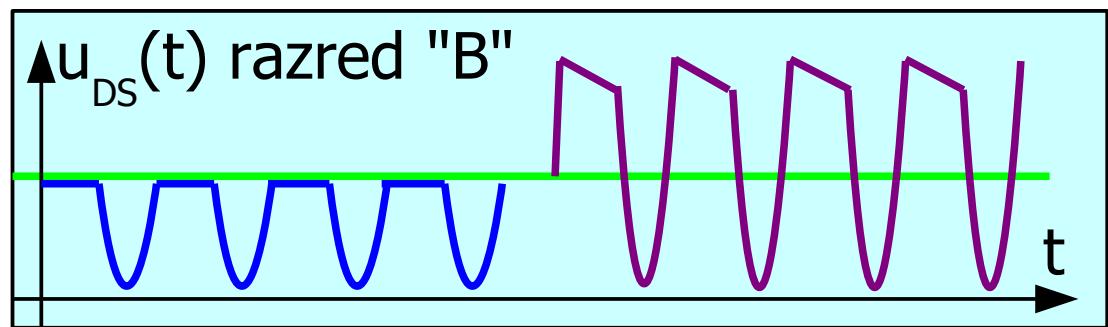
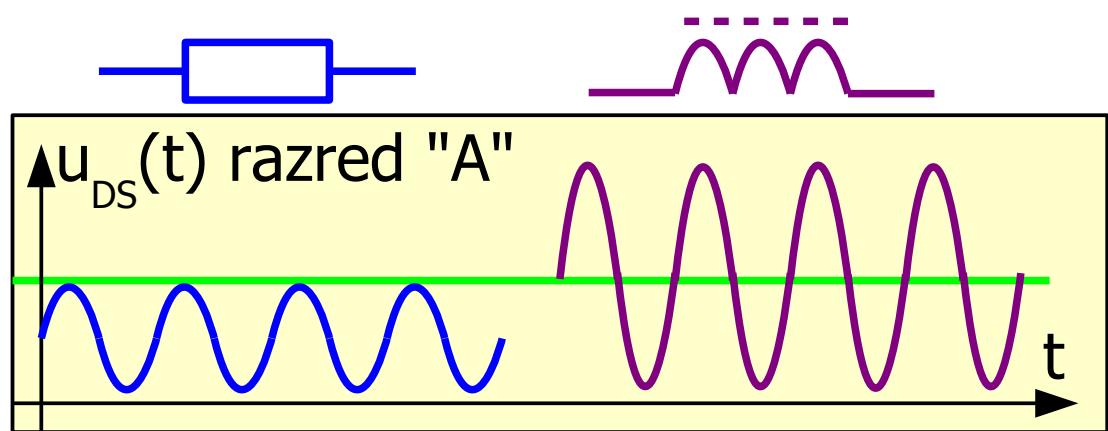
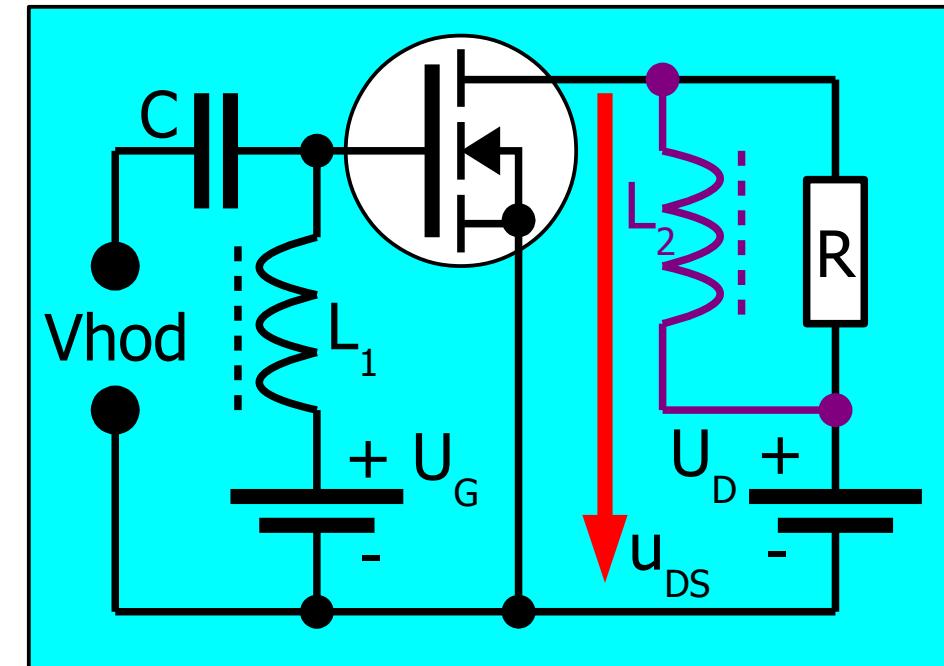
Inducirani kanal P
(P-enhancement)



Siromašeni kanal P
(P-depletion)

Vrste MOS tranzistorjev

$$I_D = k \cdot (U_{GS} - U_T)^2$$



Popačenje v delovnih točkah A, B, C in dualni B

